

# Cree<sup>®</sup> EZ700<sup>™</sup> Gen II LED Data Sheet CxxxEZ700-Sxx000-2

Cree's EZBright<sup>TM</sup> LEDs are the next generation of solid-state LED emitters that combine highly efficient InGaN materials with Cree's proprietary optical design and device technology to deliver superior value for high-intensity LEDs. The optical design maximizes light extraction efficiency and enables a Lambertian radiation pattern. Additionally, these LEDs are die attachable with conductive epoxy, solder paste or solder preforms, in addition to using the flux eutectic method. These vertically structured, low forward voltage LED chips are approximately 170 microns in height. Cree's  $EZ^{TM}$  chips are tested for conformity to optical and electrical specifications. These LEDs are useful in a broad range of applications, such as general illumination, automotive lighting and LCD backlighting.

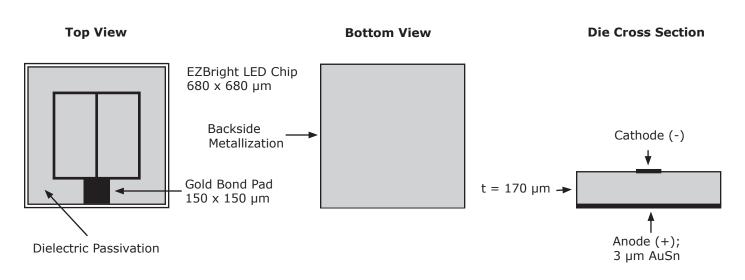
# **FEATURES**

- EZBright Power Chip LED Rf Performance
  - 240 mW min. 450 & 460 nm
  - 200 mW min. 470 nm
- Lambertian Radiation
- Conductive Epoxy, Solder Paste or Preforms, or Flux Eutectic Attach
- Low Forward Voltage 3.6 V Typical at 350 mA
- Single Wire Bond Structure
- Dielectric Passivation Across Epi Surface

## **APPLICATIONS**

- General Illumination
  - Aircraft
  - Decorative Lighting
  - Task Lighting
  - Outdoor Illumination
- White LEDs
- Crosswalk Signals
- Backlighting
- Automotive

# CxxxEZ700-Sxx000-2 Chip Diagram





Maximum Ratings at T <sub>A</sub> = 25°C Note 1	CxxxEZ700-Sxx000-2
DC Forward Current	750 mA
Peak Forward Current	1000 mA Note 3
LED Junction Temperature	145°C
Reverse Voltage	5 V
Operating Temperature Range	-40°C to +100°C
Storage Temperature Range	-40°C to +120°C

Typical Electrical/Optical Characteristics at T <sub>A</sub> = 25°C, If = 350 mA Note 2								
Part Number	Forward Voltage (V <sub>,</sub> , V)		(V <sub>f</sub> , V)	Reverse Current [I(Vr=5 V), μΑ]	Full Width Half Max (λ <sub>p</sub> , nm)			
	Min.	Тур.	Max.	Max.	Тур.			
C450EZ700-Sxx000-2	3.0	3.6	3.9	2	20			
C460EZ700-Sxx000-2	3.0	3.6	3.9	2	21			
C470EZ700-Sxx000-2	3.0	3.6	3.9	2	22			

Mechanical Specifications CxxxEZ700-Sxx000-2		
Description	Dimension	Tolerance
P-N Junction Area (μm)	650 x 650	±35
Chip Area (µm)	680 x 680	±35
Chip Thickness (µm)	170	±25
Top Au Bond Pad (µm)	150 x 150	±25
Au Bond Pad Thickness (μm)	3.0	±1.5
Back Contact Metal Area (µm)	680 x 680	±35
Back Contact Metal Thickness (µm)	3.0	±1.5

#### **Notes:**

- 1. Maximum ratings are package-dependent. The above ratings were determined using a Au-plated TO39 header without an encapsulant for characterization. Ratings for other packages may differ. The junction temperature should be characterized in a specific package to determine limitations. Assembly processing temperature must not exceed 325°C (< 5 seconds). See Cree EZBright Applications Note for assembly-process information.
- 2. All products conform to the listed minimum and maximum specifications for electrical and optical characteristics when assembled and operated at 350 mA within the maximum ratings shown above. Efficiency decreases at higher currents. Typical values given are within the range of average expected by the manufacturer in large quantities and are provided for information only. All measurements were made using a Au-plated TO39 header without an encapsulant. Optical characteristics measured in an integrating sphere using Illuminance E.
- 3. This peak forward current specification is based on a 400-ms pulse width at a 1/5-duty cycle with a junction temperature of 65°C.

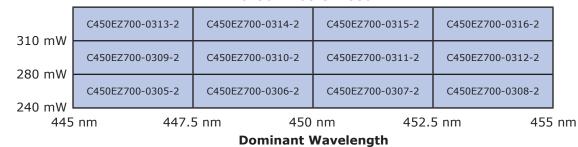


Radiant Flux

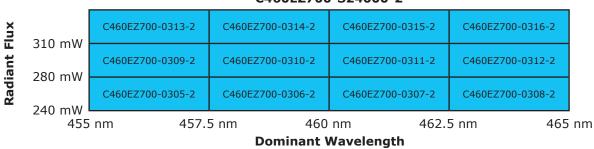
# Standard Bins for CxxxEZ700-Sxx000-2

LED chips are sorted to the **radiant flux** and **dominant wavelength** bins shown. A sorted die sheet contains die from only one bin. Sorted die kit (CxxxEZ700-Sxx000-2) orders may be filled with any or all bins (CxxxEZ700-0xxx-2) contained in the kit. All radiant flux and all dominant wavelength values shown and specified are at If = 350 mA. Radiant flux values are measured using Au-plated TO39 headers without an encapsulant.

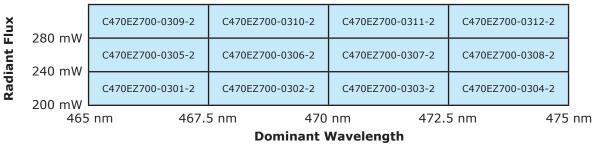
#### C450EZ700-S24000-2



## C460EZ700-S24000-2



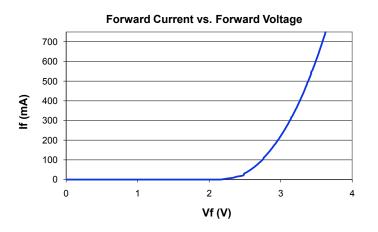
## C470EZ700-S20000-2

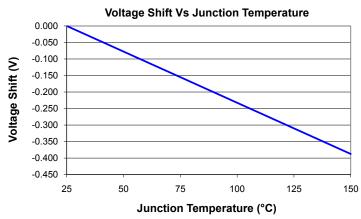


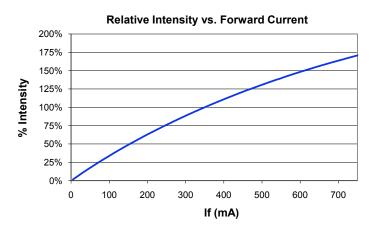


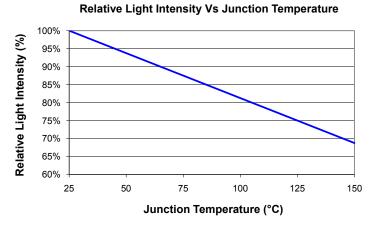
## **Characteristic Curves**

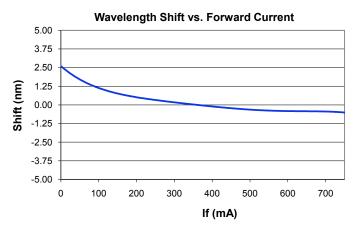
These are representative measurements for the EZBright Power Chip LED product. Actual curves will vary slightly for the various radiant flux and dominant wavelength bins.

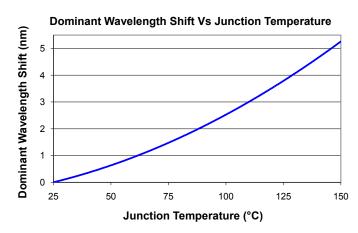














# **Radiation Pattern**

This is a representative radiation pattern for the EZBright Power Chip LED product. Actual patterns will vary slightly for each chip.

